Department of Electronic and Telecommunication Engineering

University of Moratuwa, Sri Lanka

EN 2110 - Electronics - III

Group Project

Report

Submitted by

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Name	Index	Contribution
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Table 1: Contributions of each member

Contents

1 Parasitic effect in Timing analysis

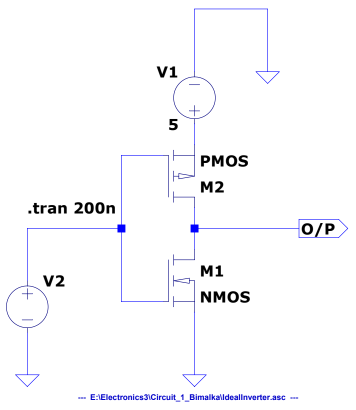
Objective: *Design a 3 stage (3 inverters) ring oscillator. Find the correlation of the parasitic effect in the oscillation period.*

1.1 System Design

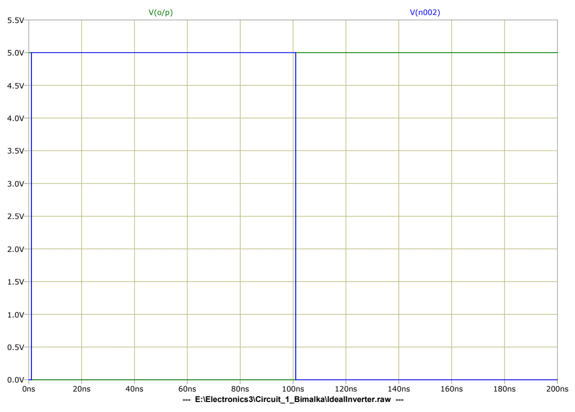
Ring oscillator is a combination of delay stages arranged in series to form a closed loop chain. It consists of an ***odd number of identical inverters (NOT gates)*** and it has an periodically oscillating output. The period of oscillation(T) of a ring oscillator can be expressed as follows where n is the number of cascaded NOT gates and τ_d is the propagation delay of a single inverter(per stage).

$$T = 2.n.\tau_d \quad \implies Oscillation\ frequency = \frac{1}{2.n.\tau_d}$$

Following figure illustrates the input output characteristic of an ideal inverter. There, output is changed as soon as the input signal changes.

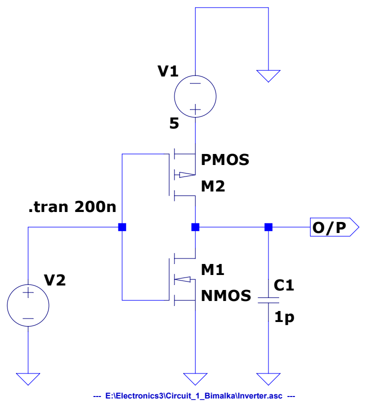


(a) Ideal Inverter Model

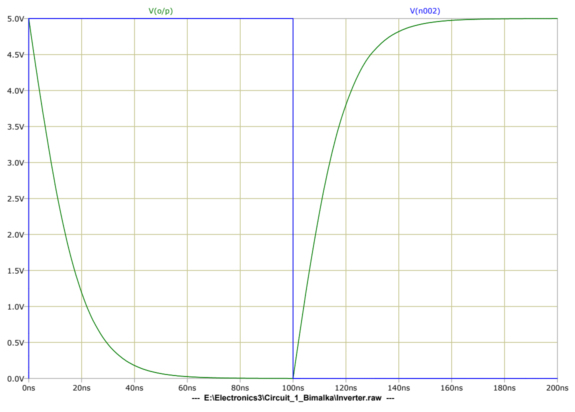


(b) Ideal inverter Output

Whereas the below figure illustrates the input output characteristic of a single stage of a general Ring Oscillator. It can be observed that finite amount of time delay is required for output to be valid for a given valid input.



(c) Inverter Model with additional delay element



(d) Effect of Parasitic Capacitance

Basic structure of a ring oscillator can be depicted as follows.

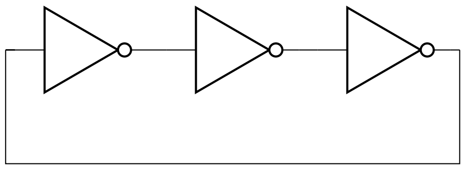


Figure 1: Basic structure of a 3 stage ring oscillator

This can be implemented using enhanced NMOS and PMOS as illustrated in the following schematic. Each inverter consists of

1.2 simulation Results and Discussion

Following ring oscillator schematic, which was taken from[1] is used to simulate the effect of parasitic capacitance of the CMOS on the period of the output waveform.

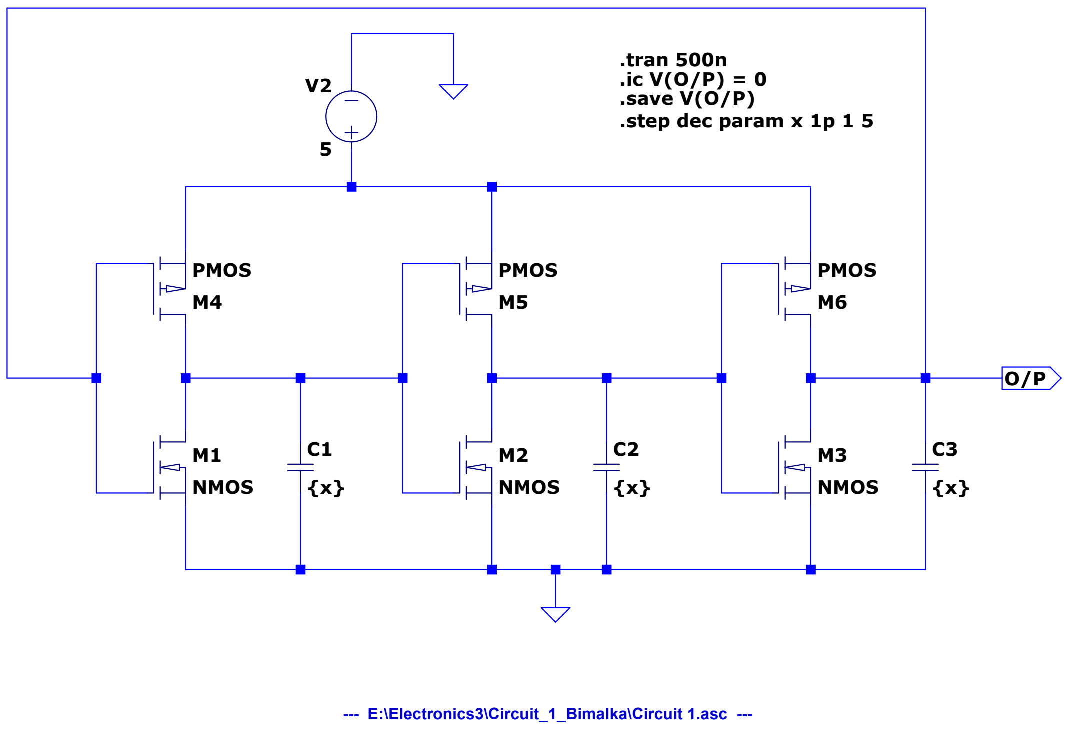


Figure 2: 3 stages enhanced CMOS Ring Oscillator

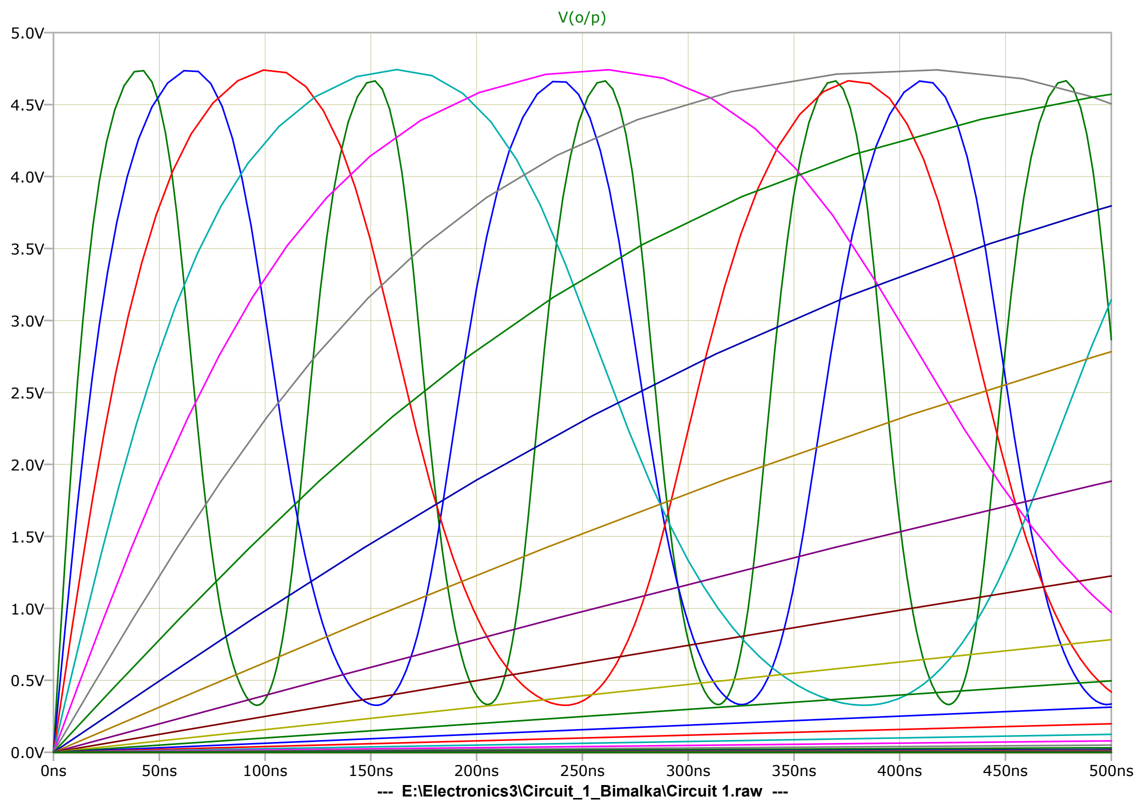


Figure 3: Waveform for Voltages of 3 stages enhanced CMOS Ring Oscillator

2 PLD

2.1 Part 1

Objective: *Design a programmable logic block to configure it as a 'NAND' or a 'NOR' gate using a single selection bit.*

First a truth table is drawn for this part considering a single selection bit (S) with two inputs (A, B) such that S=0 for 'NAND' and S=1 for 'NOR' operations respectively.

S	A	B	F
0	0	0	1
0	0	1	1
0	1	0	1
0	1	1	0
1	0	0	1
1	0	1	0
1	1	0	0
1	1	1	0

Table 2: The truth table

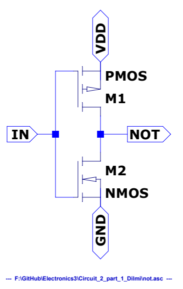
Then the relevant logic expression was obtained using a karnaugh map and it was further simplified to obtain the combination of 'NAND' and 'NOR' operations.

S\AB	00	01	11	10
0	1	1	0	1
1	1	0	0	0

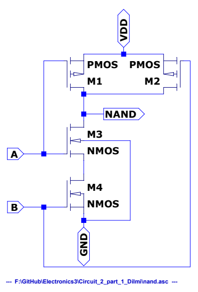
Table 3: Karnough Map for the above truth table

$$\begin{aligned} F &= \overline{S}.\overline{A} + \overline{S}.\overline{B} + \overline{A}.\overline{B} \\ &= \overline{S}.(\overline{A} + \overline{B}) + \overline{A}.\overline{B} \\ &= \overline{S}.(\overline{A.B}) + \overline{A + B} \\ &= \overline{S + A.B} + \overline{A + B} \\ &= \overline{(S + A.B).(A + B)} \\ &= \overline{(S + \overline{\overline{A.B}}).(\overline{\overline{A + B}})} \end{aligned}$$

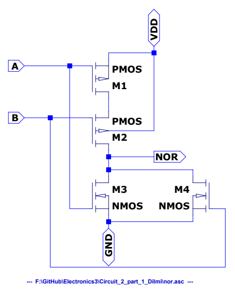
So, the resultant combinational logic circuit is as follows. (2 NANDs, 2 NORs, 3 NOTs) For the implementation of this circuit; 'NOT', 'NAND', and 'NOR' gates were designed using 'NMOS' and 'PMOS' transistors. Their schematics in LTspice are depicted below.



(a) Schematic of NOT gate



(b) Schematic of NAND gate



(c) Schematic of NOR gate

Figure 4: Basic Gates in the CMOS logic

Finally, the PLD block is designed using the above gates and the waveforms were obtained.

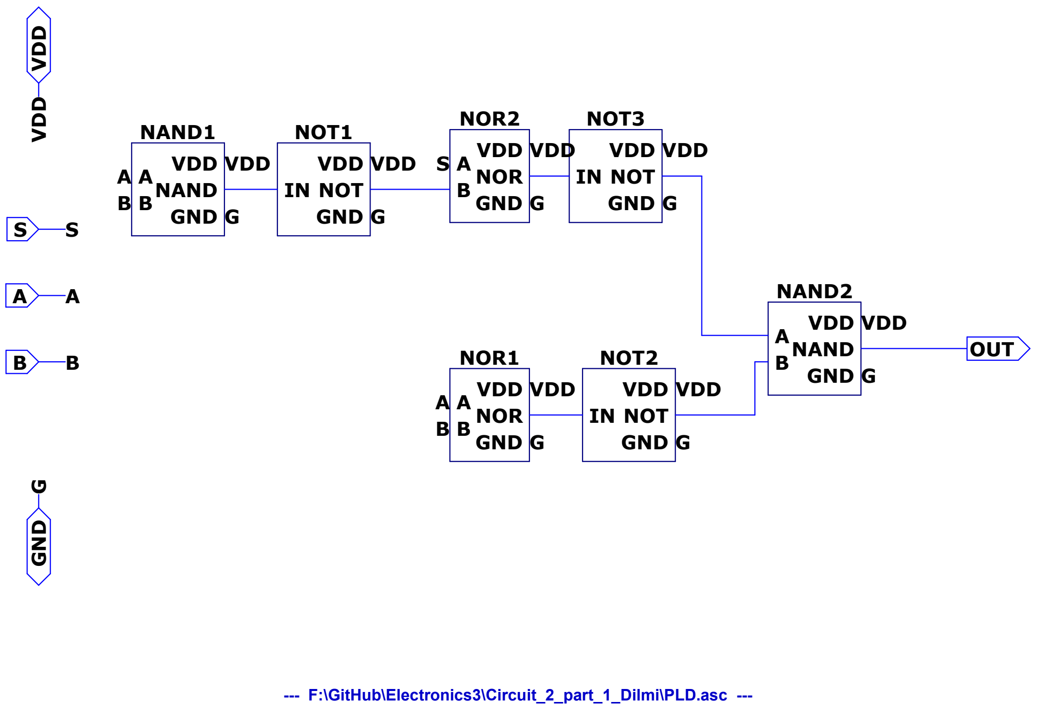

VDD
VDD
S
A
B
G
GND
NAND1
NOT1
NOR2
NOT3
NAND2
NOR1
NOT2
OUT
--- F:\GitHub\Electronics3\Circuit_2_part_1_Dilmi\PLD.asc ---

Figure 5: Circuit designed using logic blocks

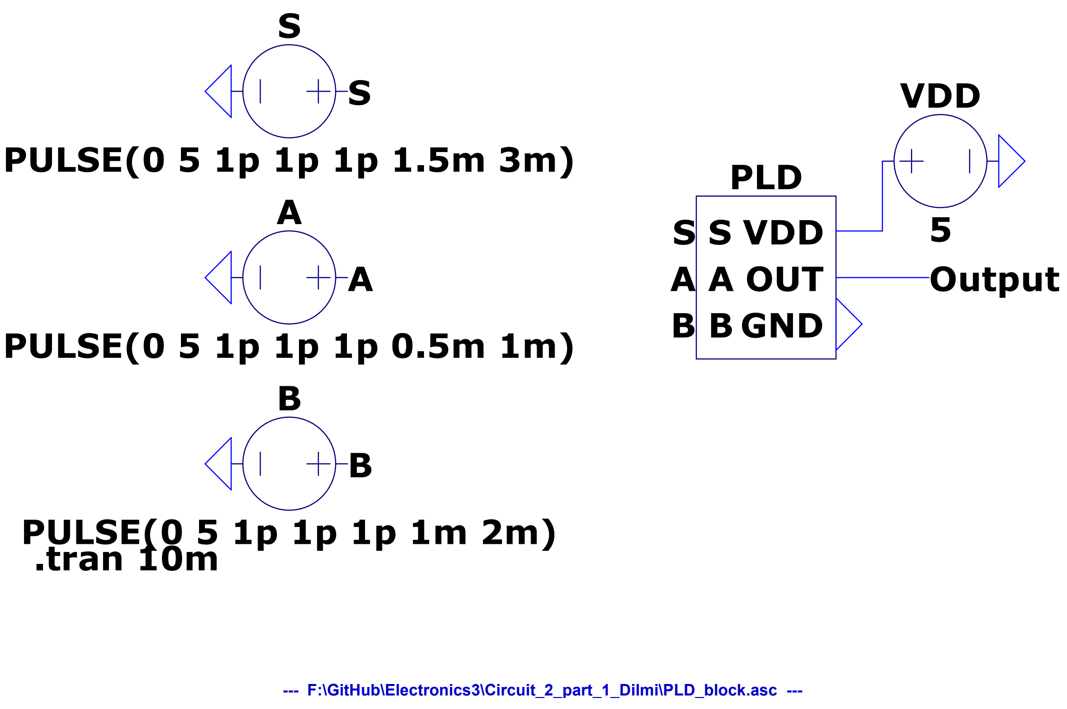

S
PULSE(0 5 1p 1p 1p 1.5m 3m)
A
PULSE(0 5 1p 1p 1p 0.5m 1m)
B
PULSE(0 5 1p 1p 1p 1m 2m)
.tran 10m
PLD
S VDD
A OUT
B GND
VDD
5
Output
--- F:\GitHub\Electronics3\Circuit_2_part_1_Dilmi\PLD_block.asc ---

Figure 6: Designed PLD block

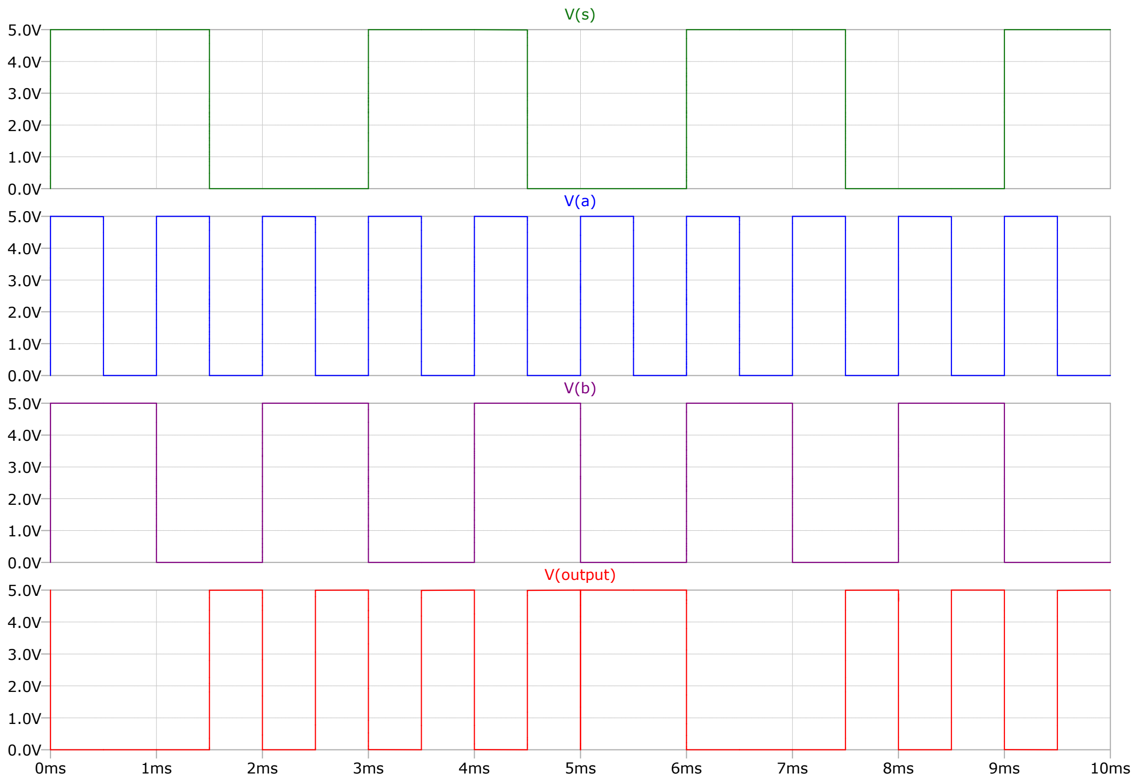


Figure 7: Waveforms for inputs and output of PLD

2.2 Part 2

Objective: *Design a single switch matrix using six pass transistors.*

In this part, the single switch matrix is needed to be designed using six pass transistors. So as the first step, a pass transistor was designed and its performance was checked. Simply an 'NMOS' transistor is fed with a switch, could be used for this task. So when the switch is on, the input signal will be received at the output (Threshold voltage is considering as zero since an ideal nmos). Also capacitors were used to ground the high impedance state which occurred when the NMOS is OFF.

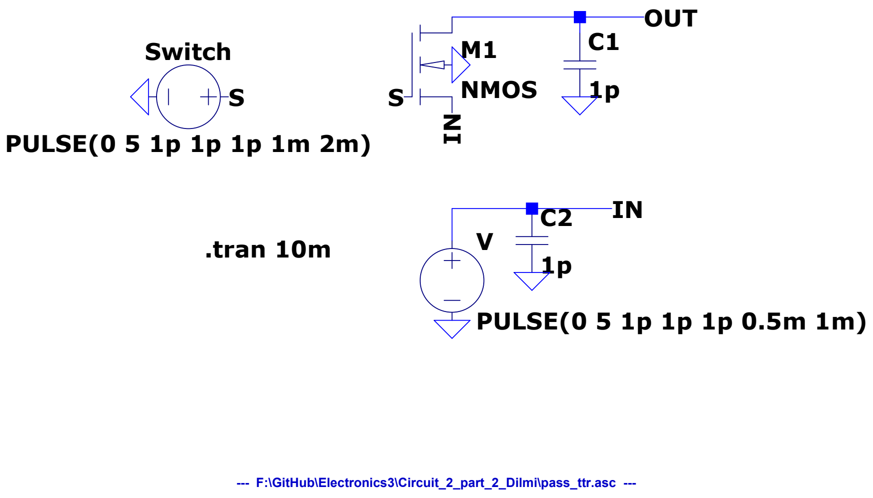

Switch
S
PULSE(0 5 1p 1p 1p 1m 2m)
S
M1
NMOS
IN
OUT
C1
1p
.tran 10m
V
C2
1p
IN
PULSE(0 5 1p 1p 1p 0.5m 1m)
--- F:\GitHub\Electronics3\Circuit_2_part_2_Dilmi\pass_ttr.asc ---

Figure 8: Schematic diagram of the pass transistor

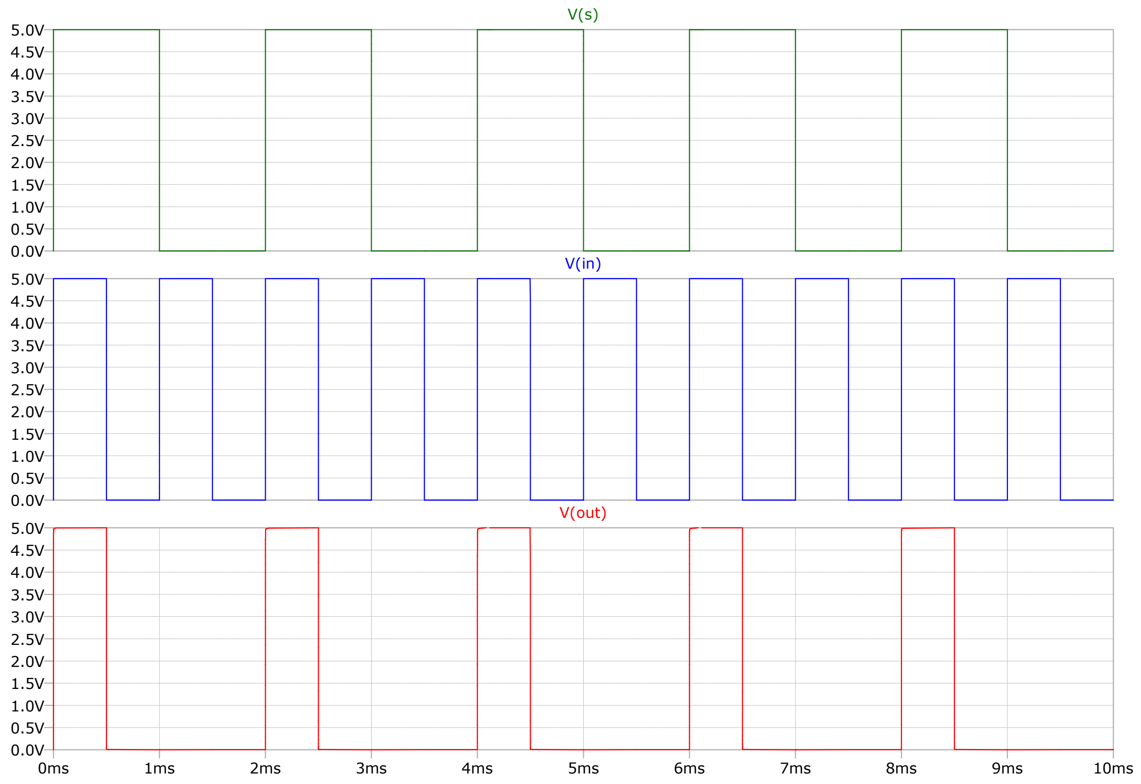


Figure 9: Waveform of the pass transistor

Then using six such transistors, the single switch matrix was designed and the schematic diagram of it is shown below.

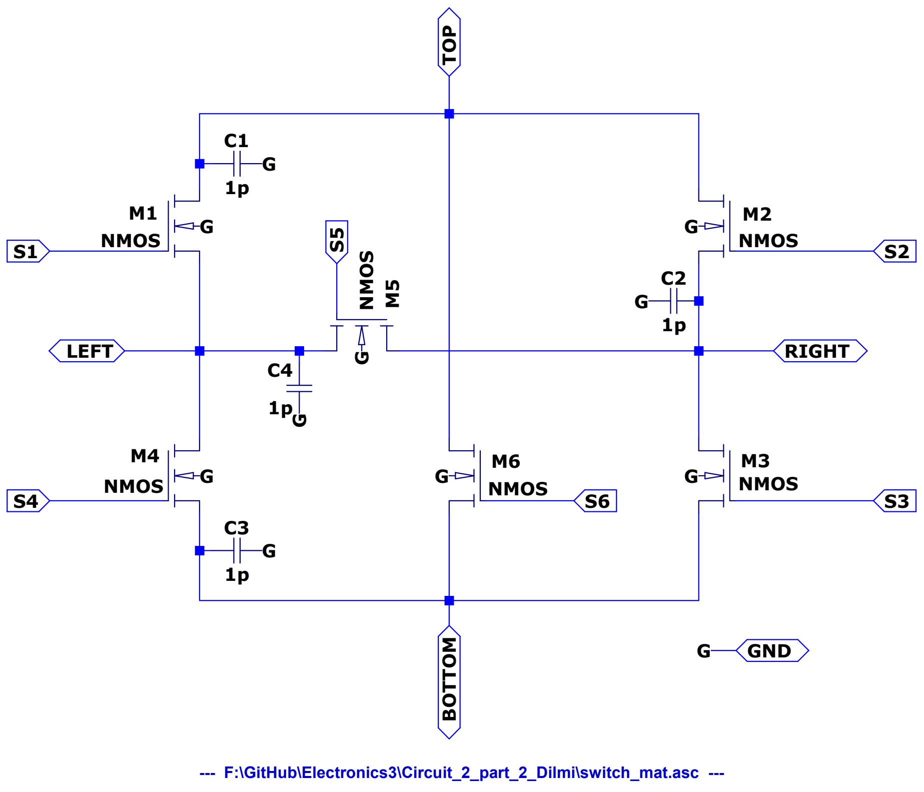


Figure 10: Schematic diagram of the single switch matrix

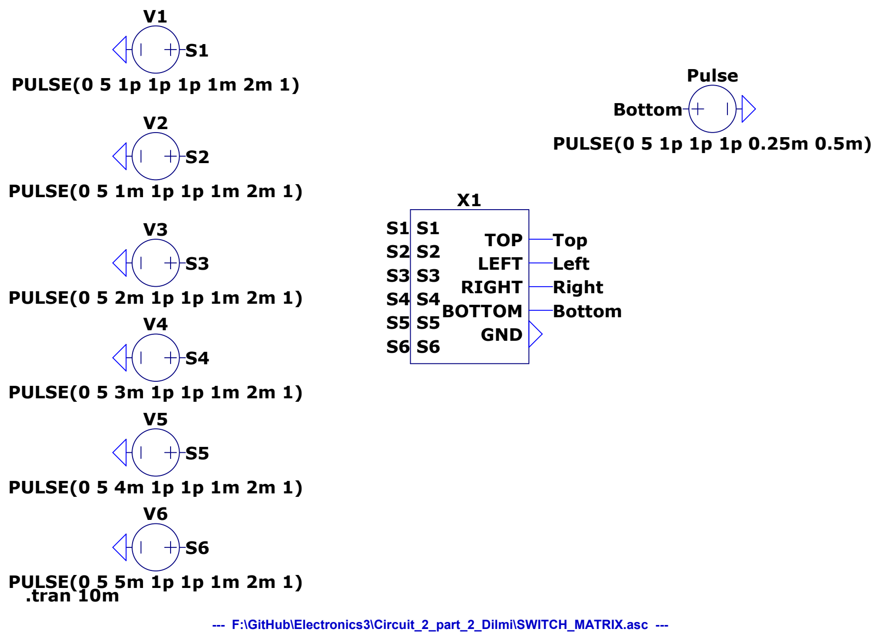

V1
S1
PULSE(0 5 1p 1p 1p 1m 2m 1)
V2
S2
PULSE(0 5 1m 1p 1p 1m 2m 1)
V3
S3
PULSE(0 5 2m 1p 1p 1m 2m 1)
V4
S4
PULSE(0 5 3m 1p 1p 1m 2m 1)
V5
S5
PULSE(0 5 4m 1p 1p 1m 2m 1)
V6
S6
PULSE(0 5 5m 1p 1p 1m 2m 1)
.tran 10m
Pulse
Bottom
PULSE(0 5 1p 1p 1p 0.25m 0.5m)
X1
S1 S1
S2 S2
S3 S3
S4 S4
S5 S5
S6 S6
TOP
LEFT
RIGHT
BOTTOM
GND
Top
Left
Right
Bottom
--- F:\GitHub\Electronics3\Circuit_2_part_2_Dilmi\SWITCH_MATRIX.asc ---

Figure 11: Designed single switch matrix block

Finally the functionality of the circuit was checked by giving pulses to left, right, top, and bottom corners separately and switching on the switches at different periods.

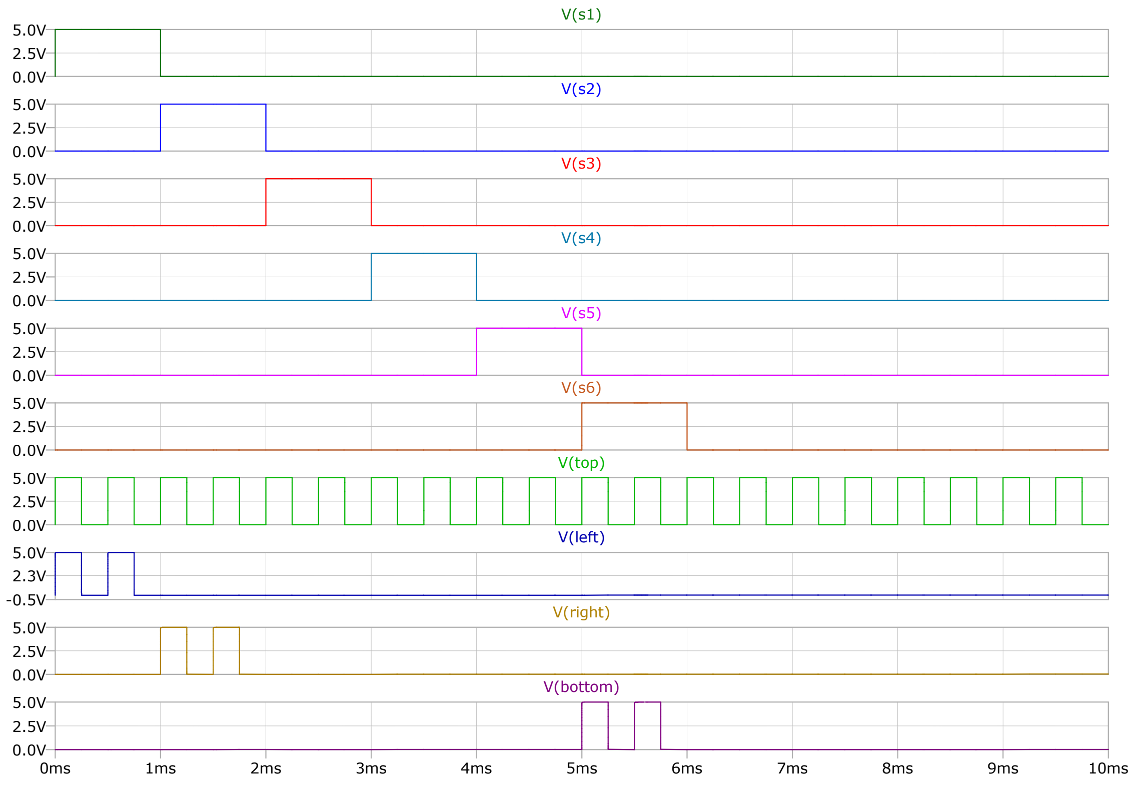


Figure 12: Waveforms when the top terminal is fed with a pulse

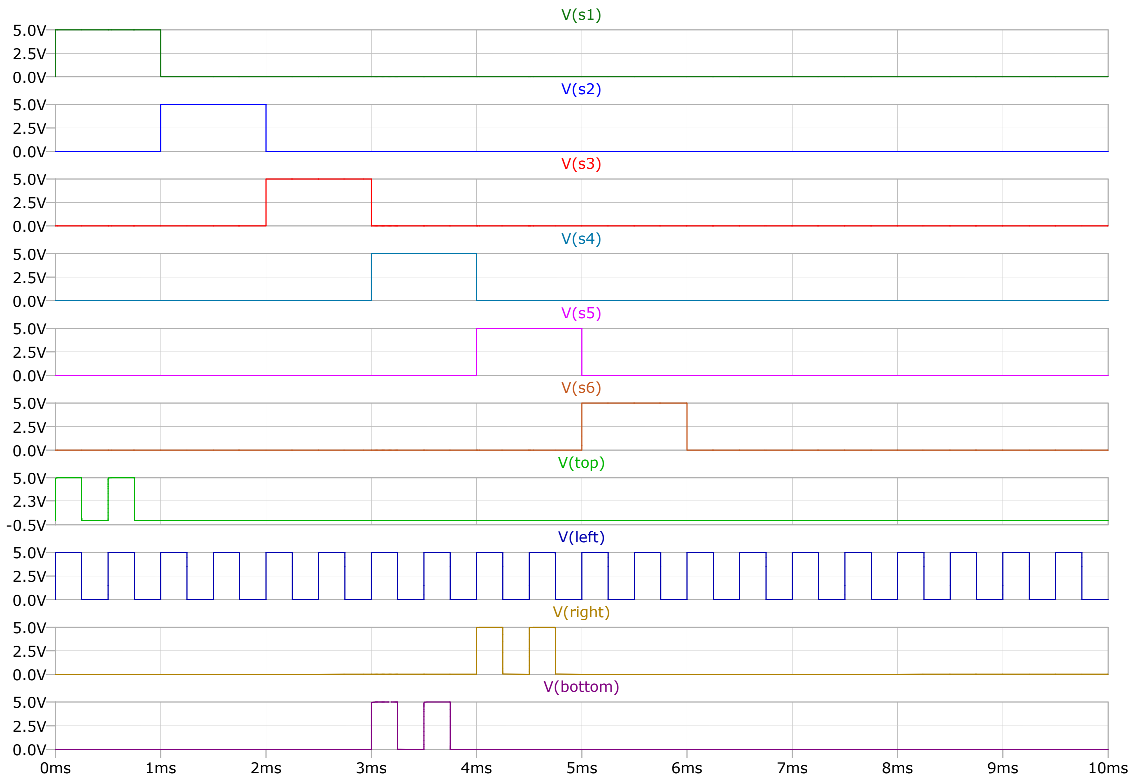


Figure 13: Waveforms when the left terminal is fed with a pulse

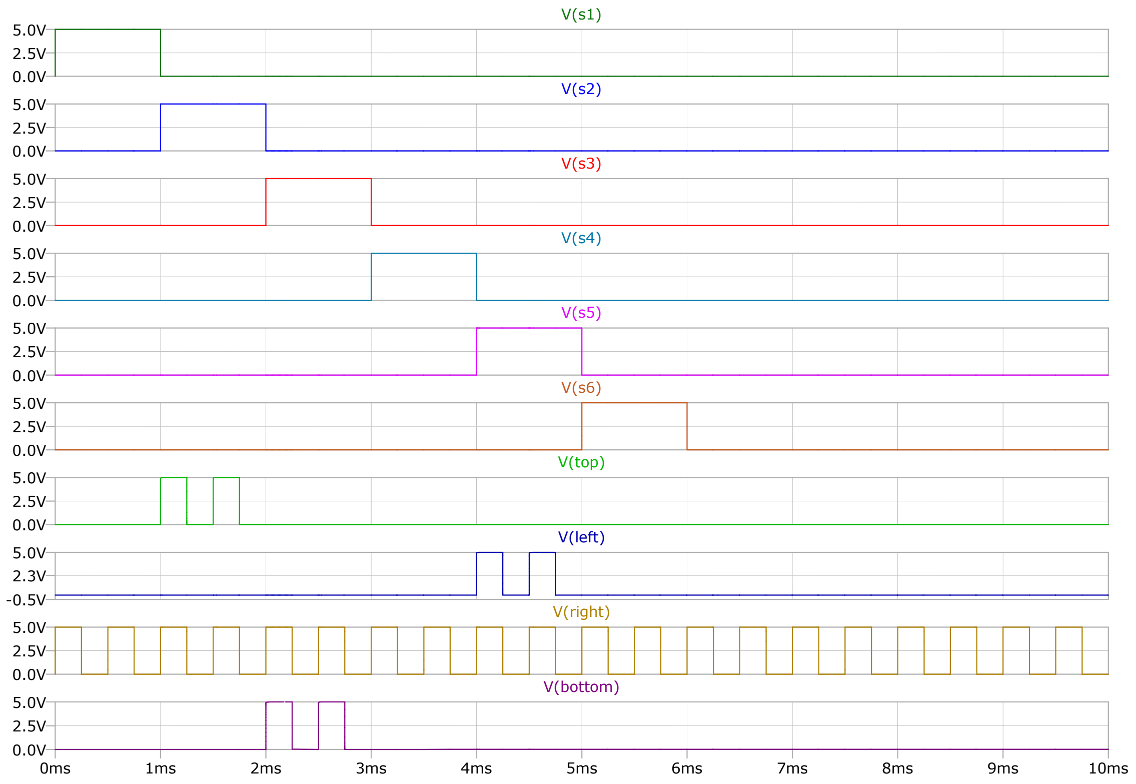


Figure 14: Waveforms when the right terminal is fed with a pulse

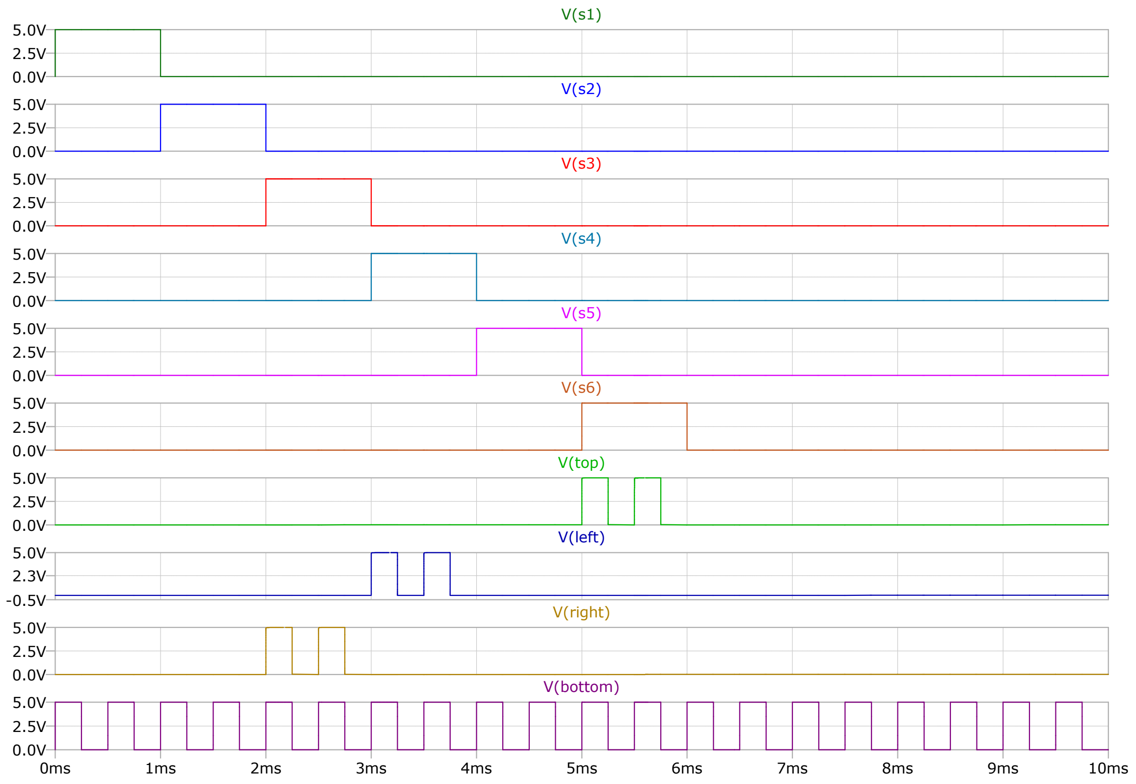


Figure 15: Waveforms when the bottom terminal is fed with a pulse

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2.3 Part 3

Objective: *Design a PLD that can be used to design any 3 input combinational circuit.*

The task was to design a PLD circuit capable of implementing any three input combinational circuit. The truth-table of any three input combinational circuits will be as below.

A	B	C	Output
0	0	0	S_1
0	0	1	S_2
0	1	0	S_3
0	1	1	S_4
1	0	0	S_5
1	0	1	S_6
1	1	0	S_7
1	1	1	S_8

Table 4: The truth-table of any three input combinational circuit

Outputs S_1, S_2,...., S_8 differ with the combinational circuit. So we can write an expression for the combinational logic circuit using the 8 minterms. Which minterms to be selected differ according to the S1, S2,...., S8. If any S_i is 1 then the corresponding minterm is taken into the sum of products expression. If Si is 0 that corresponding minterm is discarded.

So we can build the PLD with a fixed AND plane which has all eight minterms and a programmable OR plane which can be programmed using Si terms. So our PLD becomes a PROM.

Before building the PLD the AND plane and OR plane should be created. For the fixed AND plane, we need eight minterms. A minterm is a product of any three of A, $\overline{A}$, B, $\overline{B}$, C or $\overline{C}$. So we need three input and gate. We configured a three-input AND gate using NAND, NOR, and NOT gates as below for better efficiency.

$$A.B.C = \overline{\overline{A.B.C}} = \overline{\overline{A.B} + \overline{C}}$$

Using this expression we constructed the 3 input AND gates using a minimum number of logic gates.

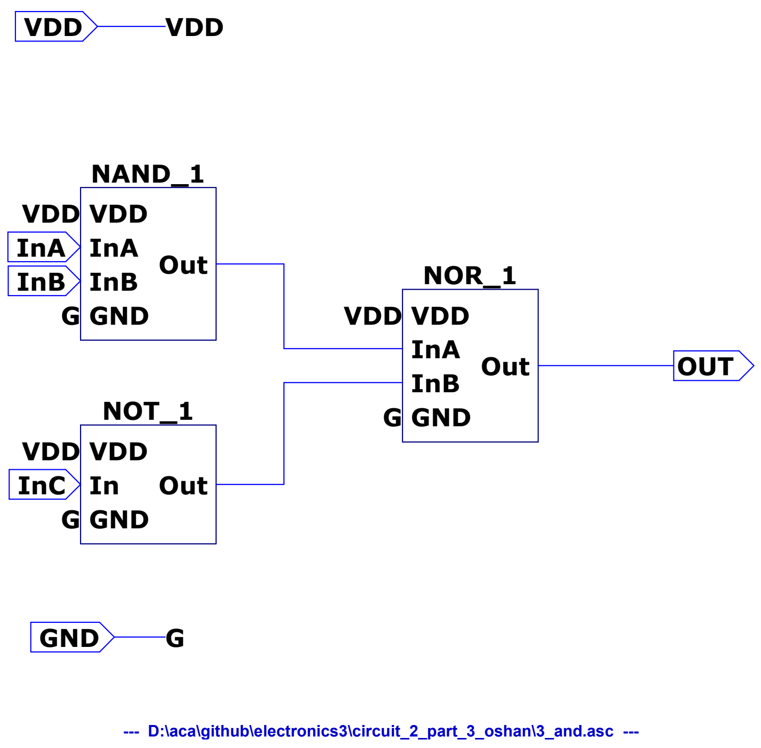

Figure 16: Implementing the three-input AND gate using NOR, AND, and NOT gates.

Using seven separate OR gates(7 NOR gates + 7 NOT gates) to implement the OR plane, increases complexity and the latency of the circuit by a huge factor. Instead, we can simplify the expression and use a minimum number of gates as below.

$$\begin{aligned}
&= S_1 + S_2 + S_3 + S_4 + S_5 + S_6 + S_7 + S_8 \\
&= \overline{\overline{S_1 + S_2 + S_3 + S_4 + S_5 + S_6 + S_7 + S_8}} \\
&= \overline{\overline{(S_1 + S_2 + S_3 + S_4)}.\overline{(S_5 + S_6 + S_7 + S_8)}} \\
&= \overline{\overline{(S_1 + S_2)}.\overline{(S_3 + S_4)}.\overline{(S_5 + S_6)}.\overline{(S_7 + S_8)}} \\
&= \overline{\overline{(S_1 + S_2)}.\overline{(S_3 + S_4)}} + \overline{\overline{(S_5 + S_6)}.\overline{(S_7 + S_8)}} \\
&= \overline{\overline{\overline{\overline{(S_1 + S_2)}.\overline{(S_3 + S_4)}} + \overline{\overline{(S_5 + S_6)}.\overline{(S_7 + S_8)}}}}
\end{aligned}$$

Using this expression we were able to build an OR plane with a minimum number of components as below.

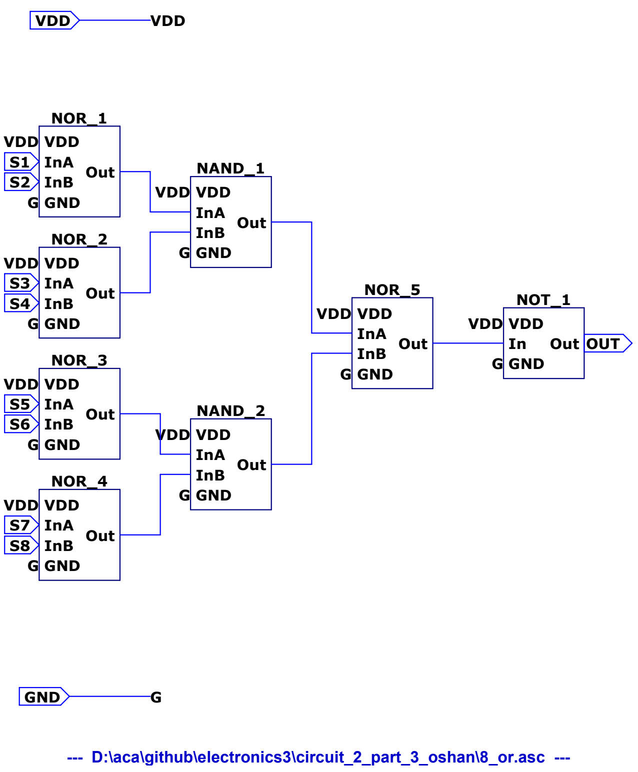

Figure 17: Implementing the OR plane

Instead of using a total of 14 logic gates, now we have implemented it using only 8 logic gates. This reduces the latency and complexity by a huge factor.

PROM is constructed as below

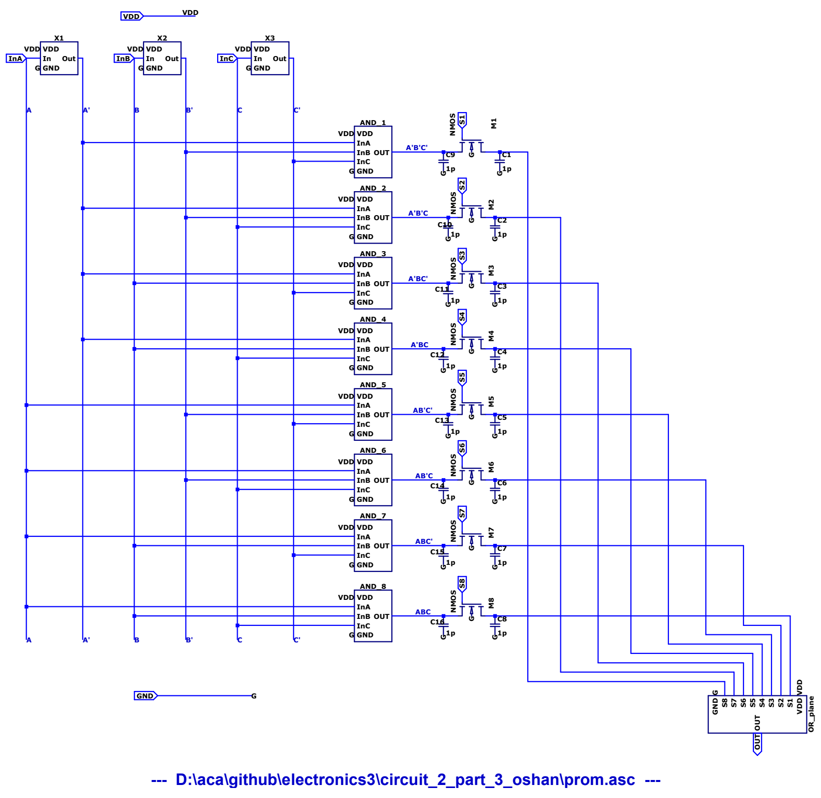

Figure 18: PROM circuit

We have used nmos transistors as switches which choose, which minterms are taken into the sum of products. We didn't choose passgates as switches as it increases the complexity and the latency of the circuit.

We tested the circuit for different combinational circuits by configuring Si switches. Below we have configured the PROM as a simple NOR gate.

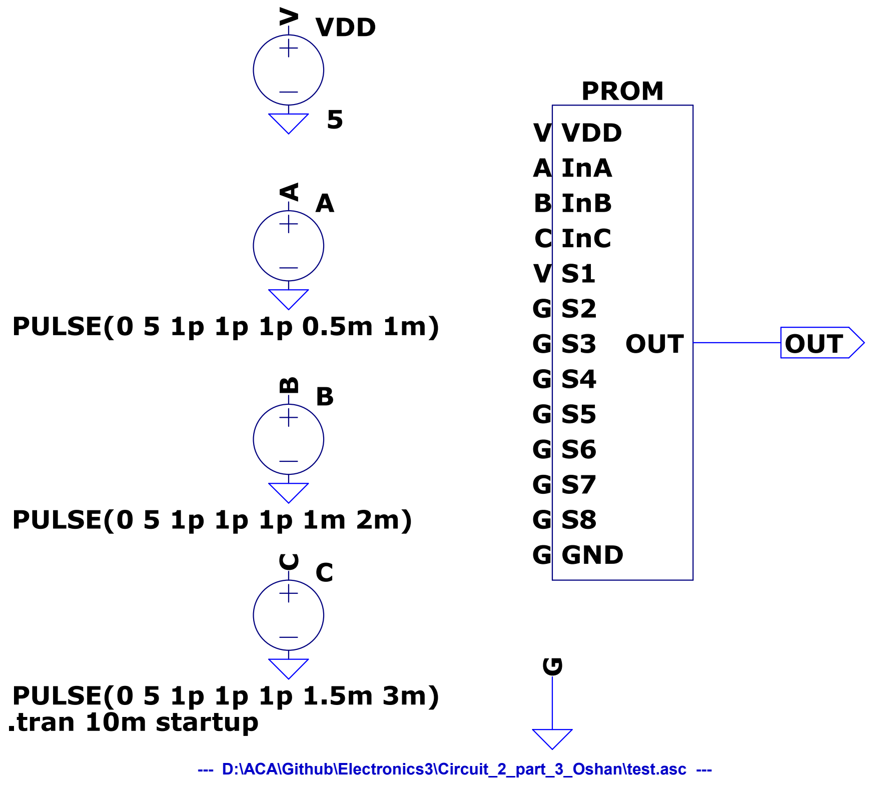
V
VDD
5
A
A
PULSE(0 5 1p 1p 1p 0.5m 1m)
B
B
PULSE(0 5 1p 1p 1p 1m 2m)
C
C
PULSE(0 5 1p 1p 1p 1.5m 3m)
.tran 10m startup
PROM
V VDD
A InA
B InB
C InC
V S1
G S2
G S3
G S4
G S5
G S6
G S7
G S8
G GND
OUT
OUT
G
--- D:\ACA\Github\Electronics3\Circuit_2_part_3_Oshan\test.asc ---

Figure 19: PROM configured as a NOR gate

Results were as below,

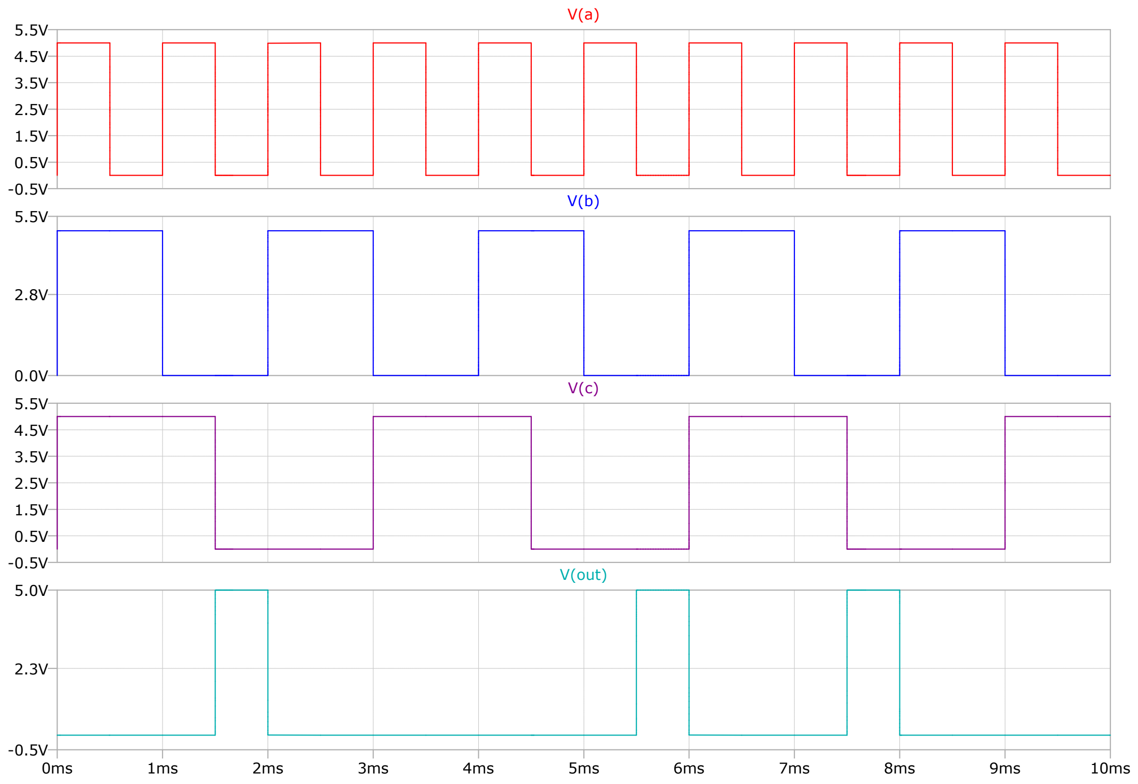

Figure 20: Results of PROM configured as a NOR gate

We can observe that the PROM is functioning correctly.

Bibliography

[1] Wikipedia contributors. Ring oscillator — Wikipedia, the free encyclopedia. https://en.wikipedia.org/w/index.php?title=Ring_oscillator&oldid=1009565738, 2021. [Online; accessed 6-May-2021].